

## Selection Guide

| Part Number  | Package                                | Packing       |
|--------------|----------------------------------------|---------------|
| A3959SB-T    | 24-pin DIP with exposed tabs           | 15 per tube   |
| A3959SLB-T   | 24-pin SOIC with internally fused pins | 31 per tube   |
| A3959SLBTR-T | 24-pin SOIC with internally fused pins | 1000 per reel |
| A3959SLP-T   | 28-pin TSSOP with exposed thermal pad  | 50 per tube   |
| A3959SLPTR-T | 28-pin TSSOP with exposed thermal pad  | 4000 per reel |

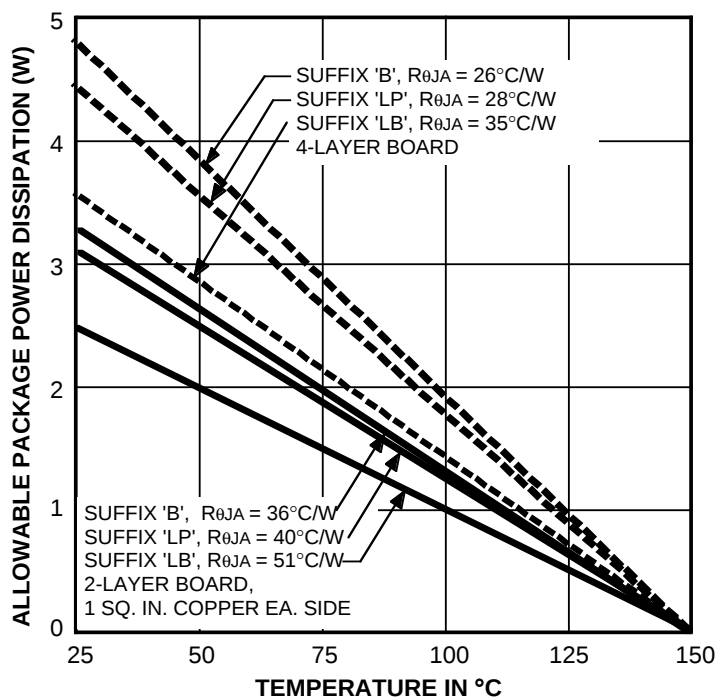
## Absolute Maximum Ratings

| Characteristic                | Symbol              | Notes                                                                                                                                                                                                  |              | Rating                        | Units |
|-------------------------------|---------------------|--------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|--------------|-------------------------------|-------|
| Load Supply Voltage           | V <sub>BB</sub>     |                                                                                                                                                                                                        |              | 50                            | V     |
| Logic Supply Voltage          | V <sub>DD</sub>     |                                                                                                                                                                                                        |              | 7.0                           | V     |
| Input Voltage                 | V <sub>IN</sub>     | Continuous                                                                                                                                                                                             |              | −0.3 to V <sub>DD</sub> + 0.3 | V     |
|                               |                     | t <sub>w</sub> < 30 ns                                                                                                                                                                                 |              | −1.0 to V <sub>DD</sub> + 1.0 | V     |
| Sense Voltage                 | V <sub>S</sub>      | Continuous                                                                                                                                                                                             |              | 0.5                           | V     |
|                               |                     | t <sub>w</sub> < 3 μs                                                                                                                                                                                  |              | 2.5                           | V     |
| Reference Voltage             | V <sub>REF</sub>    |                                                                                                                                                                                                        |              | V <sub>DD</sub>               | V     |
| Output Current                | I <sub>OUT</sub>    | Output current rating may be limited by duty cycle, ambient temperature, and heat sinking. Under any set of conditions, do not exceed the specified current rating or a junction temperature of 150°C. | Repetitive   | ±3.0                          | A     |
|                               |                     |                                                                                                                                                                                                        | Peak, < 3 μs | ±6.0                          | A     |
| Package Power Dissipation     | P <sub>D</sub>      | See Thermal Characteristics                                                                                                                                                                            |              | –                             | –     |
| Operating Ambient Temperature | T <sub>A</sub>      | Range S                                                                                                                                                                                                |              | −20 to 85                     | °C    |
| Maximum Junction Temperature  | T <sub>J(max)</sub> | Fault conditions that produce excessive junction temperature will activate the device's thermal shutdown circuitry. These conditions can be tolerated but should be avoided.                           |              | 150                           | °C    |
| Storage Temperature           | T <sub>sto</sub>    |                                                                                                                                                                                                        |              | −55 to 150                    | °C    |

## Thermal Characteristics

| Characteristic                                  | Symbol          | Test Conditions   |                                                         | Value | Units |
|-------------------------------------------------|-----------------|-------------------|---------------------------------------------------------|-------|-------|
| Package Power Dissipation                       | $P_D$           | B package         |                                                         | 3.3   | W     |
|                                                 |                 | LB package        |                                                         | 2.5   | W     |
|                                                 |                 | LP package        |                                                         | 3.1   | W     |
| Package Thermal Resistance, Junction to Ambient | $R_{\theta JA}$ | B Package         | 1-layer PCB, minimal exposed copper area                | 54    | °C/W  |
|                                                 |                 |                   | 2-layer PCB, 1-in <sup>2</sup> 2-oz copper exposed area | 36    | °C/W  |
|                                                 |                 |                   | 4-layer PCB, based on JEDEC standard                    | 26    | °C/W  |
|                                                 |                 | LB Package        | 1-layer PCB, minimal exposed copper area                | 77    | °C/W  |
|                                                 |                 |                   | 2-layer PCB, 1-in <sup>2</sup> 2-oz copper exposed area | 51    | °C/W  |
|                                                 |                 |                   | 4-layer PCB, based on JEDEC standard                    | 35    | °C/W  |
|                                                 |                 | LP Package        | 1-layer PCB, minimal exposed copper area                | 100   | °C/W  |
|                                                 |                 |                   | 2-layer PCB, 1-in <sup>2</sup> 2-oz copper exposed area | 40    | °C/W  |
|                                                 |                 |                   | 4-layer PCB, based on JEDEC standard                    | 28    | °C/W  |
| Package Thermal Resistance, Junction to Tab     | $R_{\theta JT}$ | B and LB packages |                                                         | 6     | °C/W  |
| Package Thermal Resistance, Junction to Pad     | $R_{\theta JP}$ | LP package        |                                                         | 2     | °C/W  |

\*Additional thermal information available on Allegro website.



**ELECTRICAL CHARACTERISTICS** at  $T_A = +25^\circ\text{C}$ ,  $V_{BB} = 50\text{ V}$ ,  $V_{DD} = 5.0\text{ V}$ ,  $V_{SENSE} = 0.5\text{ V}$ ,  $f_{PWM} < 50\text{ kHz}$  (unless noted otherwise)

| Characteristics                                   | Symbol              | Test Conditions                        | Min. | Typ.  | Max.            | Units |
|---------------------------------------------------|---------------------|----------------------------------------|------|-------|-----------------|-------|
| Output Drivers                                    |                     |                                        |      |       |                 |       |
| Load Supply Voltage Range                         | V <sub>BB</sub>     | Operating                              | 9.5  | –     | 50              | V     |
|                                                   |                     | During sleep mode                      | 0    | –     | 50              | V     |
| Output Leakage Current                            | I <sub>DSS</sub>    | V <sub>OUT</sub> = V <sub>BB</sub>     | –    | <1.0  | 20              | μA    |
|                                                   |                     | V <sub>OUT</sub> = 0 V                 | –    | <-1.0 | -20             | μA    |
| Output On Resistance                              | r <sub>DS(on)</sub> | Source driver, I <sub>OUT</sub> = -3 A | –    | 270   | 300             | mΩ    |
|                                                   |                     | Sink driver, I <sub>OUT</sub> = 3 A    | –    | 270   | 300             | mΩ    |
| Crossover Delay                                   |                     |                                        | 300  | 600   | 1000            | ns    |
| Body Diode Forward Voltage                        | V <sub>F</sub>      | Source diode, I <sub>F</sub> = -3 A    | –    | –     | 1.6             | V     |
|                                                   |                     | Sink diode, I <sub>F</sub> = 3 A       | –    | –     | 1.6             | V     |
| Load Supply Current                               | I <sub>BB</sub>     | f <sub>PWM</sub> < 50 kHz              | –    | 4.0   | 7.0             | mA    |
|                                                   |                     | Charge pump on, outputs disabled       | –    | 2.0   | 5.0             | mA    |
|                                                   |                     | Sleep mode                             | –    | –     | 20              | μA    |
| Control Logic                                     |                     |                                        |      |       |                 |       |
| Logic Supply Voltage Range                        | V <sub>DD</sub>     | Operating                              | 4.5  | 5.0   | 5.5             | V     |
| Logic Input Voltage                               | V <sub>IN(1)</sub>  |                                        | 2.0  | –     | –               | V     |
|                                                   | V <sub>IN(0)</sub>  |                                        | –    | –     | 0.8             | V     |
| Logic Input Current<br>(all inputs except ENABLE) | I <sub>IN(1)</sub>  | V <sub>IN</sub> = 2.0 V                | –    | <1.0  | 20              | μA    |
|                                                   | I <sub>IN(0)</sub>  | V <sub>IN</sub> = 0.8 V                | –    | <-2.0 | -20             | μA    |
| Logic Supply Current                              | I <sub>DD</sub>     | f <sub>PWM</sub> < 50 kHz              | –    | 6.0   | 10              | mA    |
|                                                   |                     | Sleep mode                             | –    | –     | 2.0             | mA    |
| ENABLE Input Current                              | I <sub>IN(1)</sub>  | V <sub>IN</sub> = 2.0 V                | –    | 40    | 100             | μA    |
|                                                   | I <sub>IN(0)</sub>  | V <sub>IN</sub> = 0.8 V                | –    | 16    | 40              | μA    |
| Internal OSC frequency                            | f <sub>OSC</sub>    | ROSC shorted to GROUND                 | 3.25 | 4.25  | 5.25            | MHz   |
|                                                   |                     | ROSC = 51 kΩ                           | 3.65 | 4.25  | 4.85            | MHz   |
| Reference Input Volt. Range                       | V <sub>REF</sub>    | Operating                              | 0.0  | –     | V <sub>DD</sub> | V     |
| Reference Input Current                           | I <sub>REF</sub>    | V <sub>REF</sub> = V <sub>DD</sub>     | –    | –     | ±1.0            | μA    |
| Comparator Input Offset Voltage                   | V <sub>IO</sub>     | V <sub>REF</sub> = 0 V                 | –    | ±5.0  | –               | mV    |

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**ELECTRICAL CHARACTERISTICS (continued)** at  $T_A = +25^\circ\text{C}$ ,  $V_{BB} = 50\text{ V}$ ,  $V_{DD} = 5.0\text{ V}$ ,  $V_{SENSE} = 0.5\text{ V}$ ,  $f_{PWM} < 50\text{ kHz}$  (unless noted otherwise)

| Characteristics             | Symbol              | Test Conditions                 | Min. | Typ. | Max.      | Units            |
|-----------------------------|---------------------|---------------------------------|------|------|-----------|------------------|
| Reference Divider Ratio     | –                   |                                 | –    | 10   | –         | –                |
| Gm Error<br>(Note 3)        | $E_{Gm}$            | $V_{REF} = V_{DD}$              | –    | –    | $\pm 4.0$ | %                |
|                             |                     | $V_{REF} = 0.5\text{ V}$        | –    | –    | $\pm 14$  | %                |
| Propagation Delay Times     | $t_{pd}$            | 0.5 $E_{in}$ to 0.9 $E_{out}$ : |      |      |           |                  |
|                             |                     | PWM change to source on         | 600  | 750  | 1200      | ns               |
|                             |                     | PWM change to source off        | 50   | 150  | 350       | ns               |
|                             |                     | PWM change to sink on           | 600  | 750  | 1200      | ns               |
|                             |                     | PWM change to sink off          | 50   | 100  | 150       | ns               |
| Thermal Shutdown Temp.      | $T_J$               |                                 | –    | 165  | –         | $^\circ\text{C}$ |
| Thermal Shutdown Hysteresis | $\Delta T_J$        |                                 | –    | 15   | –         | $^\circ\text{C}$ |
| UVLO Enable Threshold       | UVLO                | Increasing $V_{DD}$             | 3.90 | 4.2  | 4.45      | V                |
| UVLO Hysteresis             | $\Delta\text{UVLO}$ |                                 | 0.05 | 0.10 | –         | V                |

- NOTES:
1. Typical Data is for design information only.
  2. Negative current is defined as coming out of (sourcing) the specified device terminal.
  3.  $G_m$  error =  $([V_{REF}/10] - V_{SENSE})/(V_{REF}/10)$  where  $V_{SENSE} = I_{TRIP} \cdot R_S$ .

## FUNCTIONAL DESCRIPTION

**V<sub>REG</sub>.** This internally generated voltage is used to operate the sink-side DMOS outputs. The V<sub>REG</sub> terminal should be decoupled with a 0.22 µF capacitor to ground. V<sub>REG</sub> is internally monitored and in the case of a fault condition, the outputs of the device are disabled.

**Charge Pump.** The charge pump is used to generate a gate-supply voltage greater than V<sub>BB</sub> to drive the source-side DMOS gates. A 0.22 µF ceramic capacitor should be connected between CP1 and CP2 for pumping purposes. A 0.22 µF ceramic capacitor should be connected between CP and V<sub>BB</sub> to act as a reservoir to operate the high-side DMOS devices. The CP voltage is internally monitored and, in the case of a fault condition, the source outputs of the device are disabled.

**PHASE Logic.** The PHASE input terminal determines if the device is operating in the “forward” or “reverse” state.

| PHASE | OUT <sub>A</sub> | OUT <sub>B</sub> |
|-------|------------------|------------------|
| 0     | Low              | High             |
| 1     | High             | Low              |

**ENABLE Logic.** The ENABLE input terminal allows external PWM. ENABLE high turns on the selected sink-source pair. ENABLE low switches off the source driver or the source and sink driver, depending on EXT MODE, and the load current decays. If ENABLE is kept high, the current will rise until it reaches the level set by the internal current-control circuit.

| ENABLE | Outputs |
|--------|---------|
| 0      | Chopped |
| 1      | On      |

**EXT MODE Logic.** When using external PWM current control, the EXT MODE input determines the current path during the chopped cycle. With EXT MODE low, fast decay mode, the opposite pair of selected outputs will be enabled during the off cycle. With EXT MODE high, slow decay mode, both sink drivers are on with ENABLE low.

| EXT MODE | Decay |
|----------|-------|
| 0        | Fast  |
| 1        | Slow  |

**Current Regulation.** Load current is regulated by an internal fixed off-time PWM control circuit. When the outputs of the DMOS H bridge are turned on, the current increases in the motor winding until it reaches a trip value determined by the external sense resistor (R<sub>S</sub>) and the applied analog reference voltage (V<sub>REF</sub>):

$$I_{TRIP} = V_{REF}/10R_S$$

At the trip point, the sense comparator resets the source-enable latch, turning off the source driver. The load inductance then causes the current to recirculate for the fixed off-time period. The current path during recirculation is determined by the configuration of slow/mixed/fast current-decay mode via PFD1 and PFD2.

**Oscillator.** The PWM timer is based on an internal oscillator set by a resistor connected from the R<sub>OSC</sub> terminal to V<sub>DD</sub>. Typical value of 4 MHz is set with a 51 kΩ resistor. The allowable range of the resistor is from 20 kΩ to 100 kΩ.

$$f_{OSC} = 204 \times 10^9/R_{OSC}$$

If R<sub>OSC</sub> is not pulled up to V<sub>DD</sub>, it must be shorted to ground.

**Fixed Off Time.** The A3959 is set for a fixed off time of 96 cycles of the internal oscillator, typically 24 µs with a 4 MHz oscillator.

## FUNCTIONAL DESCRIPTION (continued)

**Internal Current-Control Mode.** Inputs PFD1 and PFD2 determine the current-decay method after an overcurrent event is detected at the SENSE input. In slow-decay mode, both sink drivers are turned on for the fixed off-time period. Mixed-decay mode starts out in fast-decay mode for a portion (15% or 48%) of the fixed off time, and then is followed by slow decay for the remainder of the period.

| PFD2 | PFD1 | % $t_{off}$ | Decay |
|------|------|-------------|-------|
| 0    | 0    | 0           | Slow  |
| 0    | 1    | 15          | Mixed |
| 1    | 0    | 48          | Mixed |
| 1    | 1    | 100         | Fast  |

**PWM Blank Timer.** When a source driver turns on, a current spike occurs due to the reverse-recovery currents of the clamp diodes and/or switching transients related to distributed capacitance in the load. To prevent this current spike from erroneously resetting the source-enable latch, the sense comparator is blanked. The blank timer runs after the off-time counter to provide the blanking function. The blank timer is reset when ENABLE is chopped or PHASE is changed. For external PWM control, a PHASE change or ENABLE on will trigger the blanking function. The duration is determined by the BLANK input and the oscillator.

| BLANK | $t_{blank}$  |
|-------|--------------|
| 0     | $6/f_{osc}$  |
| 1     | $12/f_{osc}$ |

**Synchronous Rectification.** When a PWM off cycle is triggered, either by an ENABLE chop command or internal fixed off-time cycle, load current will recirculate according to the decay mode selected by the control logic. The A3959 synchronous rectification feature will turn on

the appropriate pair of DMOS outputs during the current decay and effectively short out the body diodes with the low  $r_{DS(on)}$  driver. This will reduce power dissipation significantly and can eliminate the need for external Schottky diodes.

Synchronous rectification will prevent reversal of load current by turning off all outputs when a zero-current level is detected.

**Shutdown.** In the event of a fault (excessive junction temperature, or low voltage on CP or  $V_{REG}$ ) the outputs of the device are disabled until the fault condition is removed. At power up, and in the event of low  $V_{DD}$ , the UVLO circuit disables the drivers.

**Braking.** The braking function is implemented by driving the device in slow-decay mode via EXTMODE and applying an enable chop command. Because it is possible to drive current in either direction through the DMOS drivers, this configuration effectively shorts out the motor-generated BEMF as long as the ENABLE chop mode is asserted. It is important to note that the internal PWM current-control circuit will not limit the current when braking, because the current does not flow through the sense resistor. The maximum brake current can be approximated by  $V_{BEMF}/R_L$ . Care should be taken to ensure that the maximum ratings of the device are not exceeded in worst-case braking situations of high speed and high inertial loads.

**SLEEP Logic.** The SLEEP input terminal is used to minimize power consumption when not in use. This disables much of the internal circuitry including the regulator and charge pump. Logic low will put the device into sleep mode, logic high will allow normal operation.

Note: If the sleep mode is not used, connect a 5 k $\Omega$  pull-up resistor between the SLEEP terminal and  $V_{DD}$ .

**FUNCTIONAL DESCRIPTION** (continued)

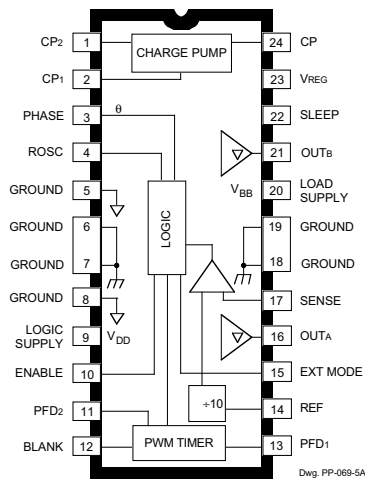
**Current Sensing.** To minimize inaccuracies in sensing the  $I_{TRIP}$  current level, which may be caused by ground trace IR drops, the sense resistor should have an independent ground return to the ground terminal of the device. For low-value sense resistors the IR drops in the PCB sense resistor's traces can be significant and should be taken into account. The use of sockets should be avoided as they can introduce variation in  $R_S$  due to their contact resistance.

The maximum value of  $R_S$  is given as  $R_S = 0.5/I_{TRIP}$ .

**Thermal Protection.** Circuitry turns off all drivers when the junction temperature reaches 165°C typically. It is intended only to protect the device from failures due to excessive junction temperatures and should not imply that output short circuits are permitted. Thermal shutdown has a hysteresis of approximately 15°C.

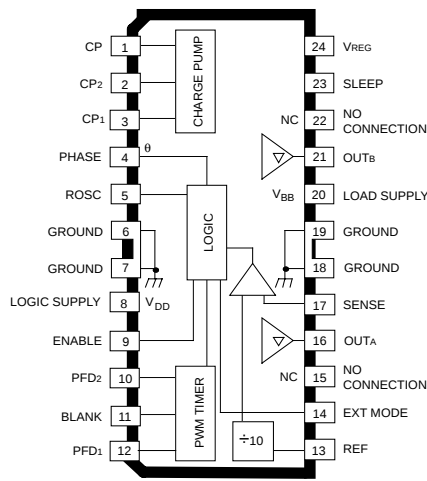
**Layout.** A star ground system located close to the driver is recommended. The printed wiring board should use a heavy ground plane. For optimum electrical and thermal performance, the driver should be soldered directly onto the board. The ground side of  $R_S$  should have an individual path to the ground terminals of the device. This path should be as short as is possible physically and should not have any other components connected to it. It is recommended that a 0.1  $\mu$ F capacitor be placed between SENSE and ground as close to the device as possible; the load supply terminal,  $V_{BB}$ , should be decoupled with an electrolytic capacitor (> 47  $\mu$ F is recommended) placed as close to the device as is possible. On the 28-lead TSSOP package, the copper ground plane located under the exposed thermal pad is typically used as a star ground.

Package B (DIP)



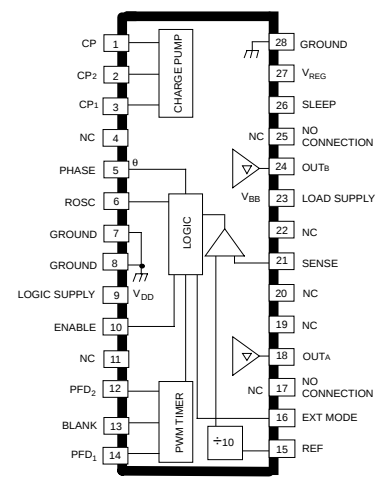
Dwg. PP-069-5A

Package LB (SOIC)



Dwg. PP-069-4

Package LP (TSSOP)

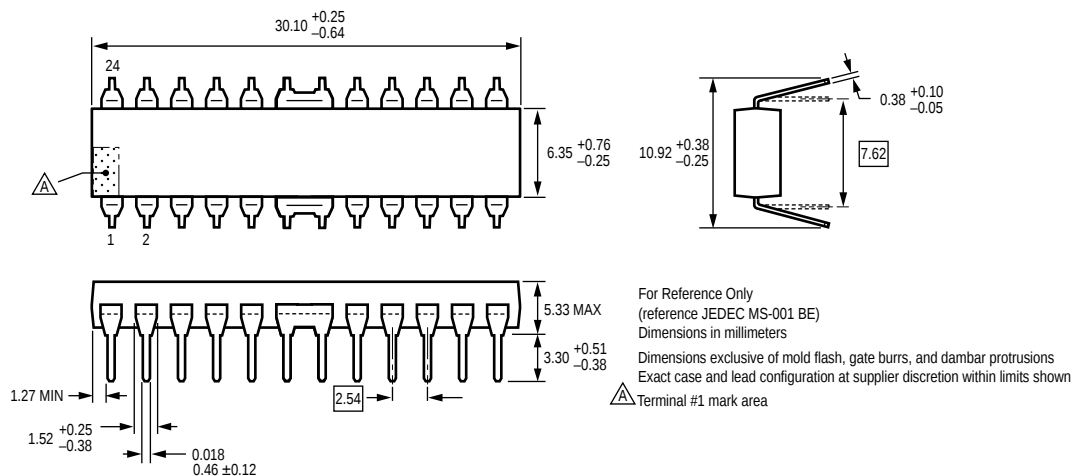


## Terminal List

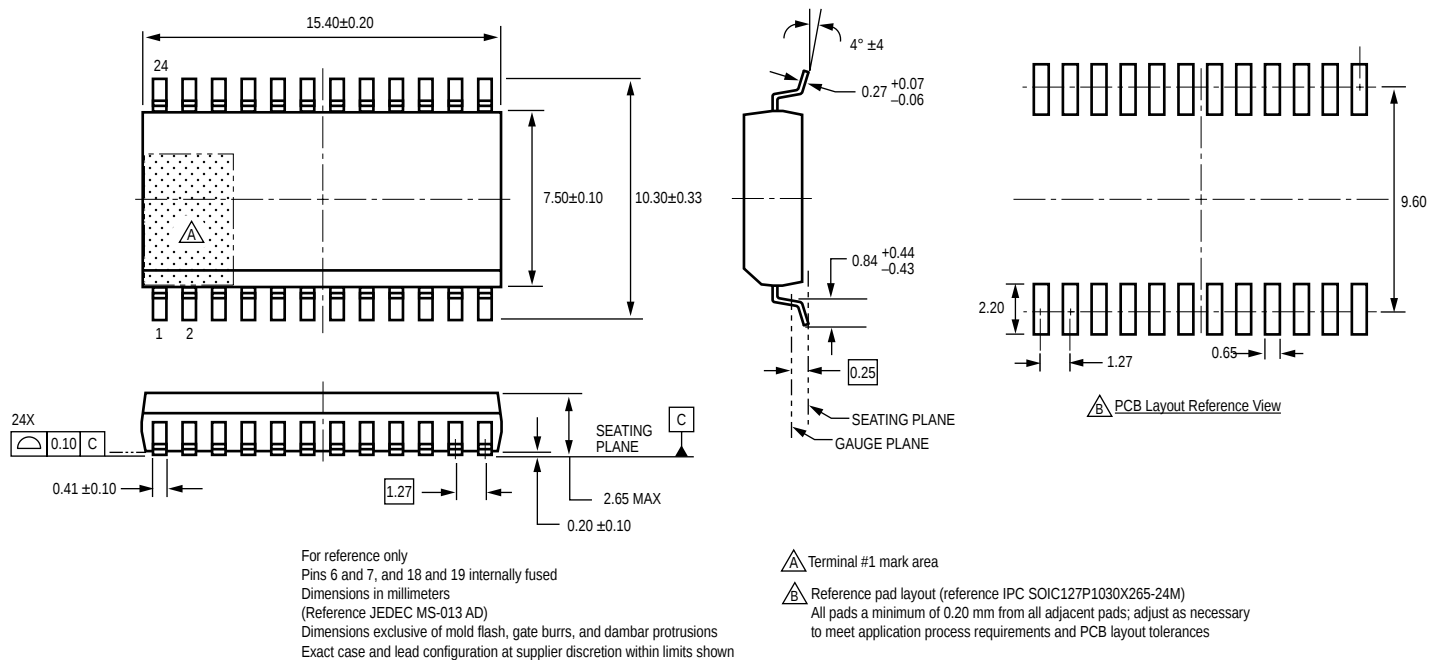
| Terminal Name | Terminal Description                                    | B (DIP)     | LB (SOIC) | LP (TSSOP) |
|---------------|---------------------------------------------------------|-------------|-----------|------------|
| CP            | Reservoir capacitor (typically 0.22 $\mu$ F)            | 24          | 1         | 1          |
| CP1 & CP2     | The charge pump capacitor (typically 0.22 $\mu$ F)      | 1 & 2       | 2 & 3     | 2 & 3      |
| NC            | No (internal) connection                                | —           | —         | 4          |
| PHASE         | Logic input for direction control                       | 3           | 4         | 5          |
| ROSC          | Oscillator resistor                                     | 4           | 5         | 6          |
| GROUND        | Grounds                                                 | 5, 6, 7, 8* | 6, 7      | 7, 8*      |
| LOGIC SUPPLY  | VDD, the low voltage (typically 5 V) supply             | 9           | 8         | 9          |
| ENABLE        | Logic input for enable control                          | 10          | 9         | 10         |
| NC            | No (internal) connection                                | —           | —         | 11         |
| PFD2          | Logic-level input for fast decay                        | 11          | 10        | 12         |
| BLANK         | Logic-level input for blanking control                  | 12          | 11        | 13         |
| PFD1          | Logic-level input for fast decay                        | 13          | 12        | 14         |
| REF           | VREF, the load current reference input voltage          | 14          | 13        | 15         |
| EXT MODE      | Logic input for PWM mode control                        | 15          | 14        | 16         |
| NO CONNECT    | No (Internal) connection                                | —           | 15        | 17         |
| OUTA          | One of two DMOS bridge outputs to the motor             | 16          | 16        | 18         |
| NC            | No (internal) connection                                | —           | —         | 19, 20     |
| SENSE         | Sense resistor                                          | 17          | 17        | 21         |
| NC            | No (internal) connection                                | —           | —         | 22         |
| GROUND        | Grounds                                                 | 18, 19*     | 18, 19    | —          |
| LOAD SUPPLY   | VBB, the high-current, 9.5 V to 50 V, motor supply      | 20          | 20        | 23         |
| OUTB          | One of two DMOS bridge outputs to the motor             | 21          | 21        | 24         |
| NO CONNECT    | No (Internal) connection                                | —           | 22        | 25         |
| SLEEP         | Logic-level Input for sleep operation                   | 22          | 23        | 26         |
| VREG          | Regulator decoupling capacitor (typically 0.22 $\mu$ F) | 23          | 24        | 27         |
| GROUND        | Ground                                                  | —           | —         | 28*        |

\* For the B (DIP) package only, there is an indeterminate resistance between the substrate grounds (pins 6, 7, 18, and 19) and the grounds at pins 5 and 8. Pins 5 and 8, and 6, 7, 18, or 19 must be connected together externally. For the LP (TSSOP) package, the grounds at terminals 7, 8, and 28 should be connected together at the exposed pad beneath the device.

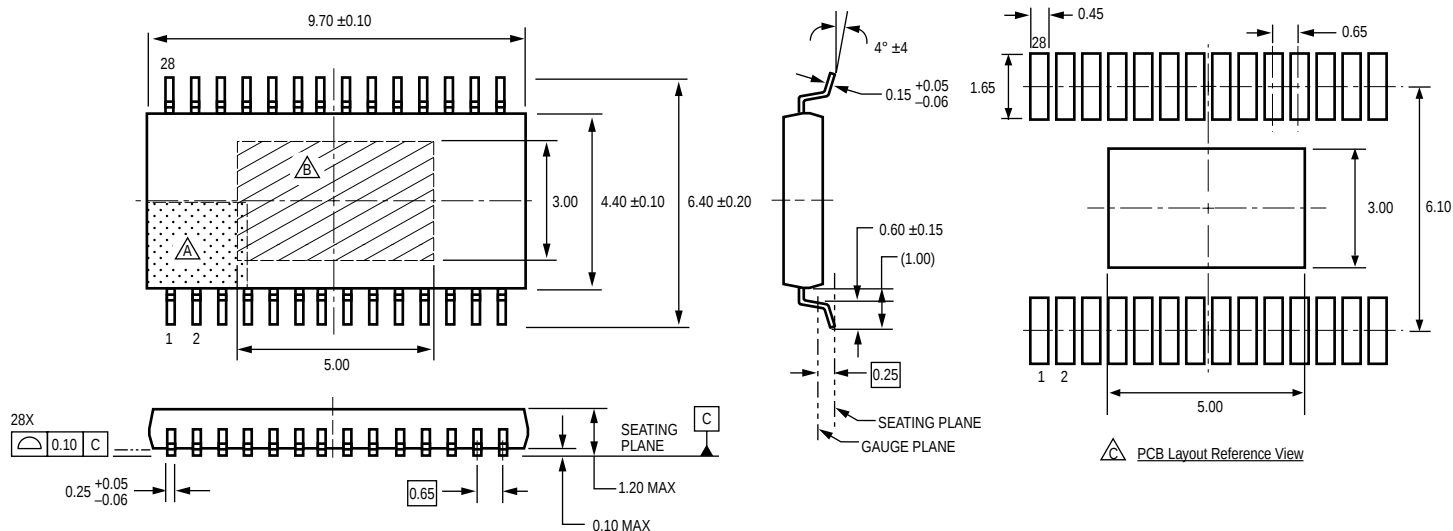
## B package 24-pin DIP



## LB package 24-pin SOICW



## LP package 28-pin TSSOP



For reference only  
(reference JEDEC MO-153 AET)  
Dimensions in millimeters  
Dimensions exclusive of mold flash, gate burrs, and dambar protrusions  
Exact case and lead configuration at supplier discretion within limits shown

- △ Terminal #1 mark area
- △ Exposed thermal pad (bottom surface)
- △ Reference land pattern layout (reference IPC7351 SOP65P640X120-29CM); All pads a minimum of 0.20 mm from all adjacent pads; adjust as necessary to meet application process requirements and PCB layout tolerances; when mounting on a multilayer PCB, thermal vias at the exposed thermal pad land can improve thermal dissipation (reference EIA/JEDEC Standard JESD51-5)

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